MLX92213

MicroPower & Low-Voltage
Hall Effect Latch with Enable

Features and Benefits

- Operating Voltage from 1.6 to 3.6V
- Latching Output Behaviour
- Micro power Consumption 48uA@3V ; 36uA@1.8V
- Advanced Power Manageability through dedicated “Enable” pin
- Ultra High Sensitivity Hall Sensor
- Push-Pull Output
- Miniature & Ultra-Thin QFN package (2mm x 1.5mm ; 0.4mm thickness)
- “Green” and “Pb-Free” Compliant Package

Applications

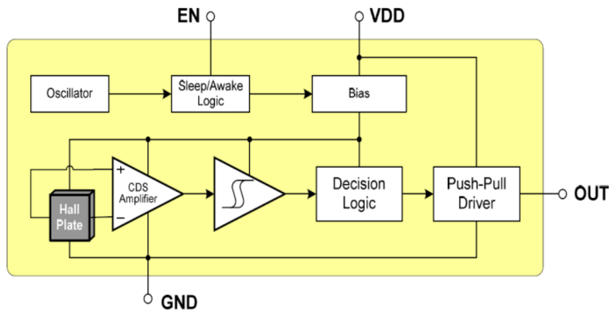
- Battery-operated / Handheld Appliances
- Rotary or Linear Contact-Less Encoders
- Scroll/Jog Wheel, Trackball (Mobile Phones, Portable Media Players, Notebooks, Computer Mice, Camcorders, Cameras,…)
- Home/Industrial Metering Equipment (Wafer Flow Meter)

Ordering information

Part No.	Temperature Code	Package Code	Comment
MLX92213ELD-AAA-000-RE	E (-40°C to 85°C)	LD (UTQFN-6L)	$B_{OP}/B_{RP}= \pm$ 2mT

Legend:
Temperature Code: E for Temperature Range -40°C to 85°C
Package Code: LD for UTQFN
Packing Form: RE for Reel
Ordering example: MLX92213ELD-AAA-000-RE

1. Functional Diagram



2. General Description

The MLX92213 Micropower Low-Voltage Latch Hall effect sensor IC is fabricated in mixed signal CMOS technology. It incorporates advanced Correlated Double Sampling (CDS) techniques to provide accurate and stable magnetic switching points. In order to save power, the internal Timing Logic alternates Awake and Sleep modes, thus significantly reducing the power consumption. The magnetic flux density is periodically evaluated against predefined thresholds. If the flux density is above/below the B_{OP}/B_{RP} thresholds, then the Output changes its state accordingly. During the Sleep mode the Output is latched in its previous state. The design has been optimized for applications requiring extended operating lifetime in battery-powered systems. The EN pin adds flexibility by enabling external control of the Micropower Period and Duty Cycle. The Push-Pull Output of the MLX92213 will be latched in Low state in the presence of a sufficiently strong South magnetic field ($B > B_{OP}$) facing the marked side of the package. The Output will be latched in High state in the presence of a sufficiently strong North magnetic field ($B < B_{RP}$).

Contents

3. Glossary of Terms

Gauss, milliTesla (mT), Units of magnetic flux density:
10 Gauss = 1mT

4. Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Supply Voltage	V_{DD}	5	V
Supply Current	I_{DD}	±10	mA
EN Input Voltage	V_{IN}	5	V
EN Input Current	I_{IN}	±10	mA
Output Voltage	V_{OUT}	5	V
Output Current	I_{OUT}	±10	mA
Operating Temperature Range	T_A	-40 to 85	°C
Storage Temperature Range	T_S	-50 to 150	°C

Table 1: Absolute maximum ratings

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5. Pinout

Pin Name	Function	Pin №
VDD	Power Supply	3
GND	Ground	4, E-pad [1]
OUT	Push-Pull Output	1
EN	Enable[2]	6
NC	Not Connected	2, 5

Table 2: Pin definitions and descriptions

LD Package

6. Output Behavior vs. Magnetic Pole

DC Operating Parameters $T_A = -40^{\circ}C$ to $85^{\circ}C$, V_{DD} = 1.6V to 3.6V

Parameter	Test Conditions	OUT
South pole	$B > B_{OP}$	Low
North pole	$B < B_{RP}$	High

Table 3: Output behavior versus magnetic pole [3]

[1] *Exposed Pad on LD package is connected to Ground.*
[2] *EN has to be connected to V_{DD} when external Micropower control is not used.*
[3] *The magnetic pole is applied facing the package top*

7. General Electrical Specifications

Operating Parameters: T_A = -40 to 85°C, V_{DD} = 1.6V to 3.6V, unless otherwise specified

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply Voltage	V_{DD}	Operating	1.6	-	3.6	V
Average Supply Current	I_{DDav}	EN = V_{DD}, V_{DD}=3V	-	48	86	µA
		EN = V_{DD}, V_{DD}=1.8V	-	36	70	µA
Awake Supply Current	I_{DDaw}	EN = V_{DD}, I_{OUT} = 0mA	-	-	4	mA
Sleep Supply Current	I_{DDsl}	EN = V_{DD}, I_{OUT} = 0mA	-	-	4.5	µA
Standby Supply Current	I_{DDsb}	EN = 0	-	-	1	µA
Output Characteristics						
High Level Output Voltage	V_{OH}	B < B_{RP}, I_{OUT} = -1mA	V_{DD}-0.4	V_{DD}-0.2	-	V
Low Level Output Voltage	V_{OL}	B > B_{OP}, I_{OUT} = 1mA	-	0.2	0.4	V
Power-On Output State[1]	V_{PO}		High			
Enable Pin Characteristics						
EN Input High Voltage	V_{IH}		0.1*V_{DD}+1	-	-	V
EN Input Low Voltage	V_{IL}		-	-	0.1*V_{DD}+0.1	V
EN Input Current	I_{IN}		-1	-	1	µA
EN Input Delay	t_{ID}		-	-	5	µs
EN Pulse Width	T_{E1}		5	-	-	µs
EN Period	T_{E2}		T_{AW} + 0.1	-	-	µs
Timing Characteristics						
Enable Transition Time [2]	t_{ET}	Disabled -> Enabled	-	-	t_{ID} + T_{AW}	µs
Disable Transition Time [3]	t_{DT}	Enabled -> Disabled	-	-	t_{ID} + T_{AW}	µs
Power-On Time[4]	t_{ON}	EN = V_{DD}	-	31	80	µs
		EN = V_{DD}, T_A=25°C, V_{DD}=3V	-	31	52	µs
Awake Time	T_{AW}	EN = V_{DD}	-	-	60	µs
		EN = V_{DD}, T_A=25°C, V_{DD}=3V	-	27	40	µs
		EN = V_{DD}, T_A=25°C, V_{DD}=1.8V	-	30	45	µs
Period	T_{PER}	EN = V_{DD}	0.70	1.30	1.90	ms
Response Time[5]	t_{RES}	EN = V_{DD}	-	-	T_{PER}	ms
Magnetic Signal Frequency	f_B	EN = V_{DD}	1 / [2 * T_{PER}]			Hz

Table 4: Electrical specification

[1] *Defined output state after Power-On Time is high until the first B_{OP} threshold is reached (B>B_{OP})*
[2] *Enable transition time defined from EN command to the update of the Output driver state (ref. to Diagrams, p.6)*
[3] *Disable transition time defined from EN command to entering Standby (ref. to Diagrams, p.6)*
[4] *Power-On Time represents the time from reaching V_{DD} = 1.6V to the update of the Output driver state*
[5] *Response Time is the time from the magnetic field change to the according update of the Output driver state, guaranteed by design*

8. Magnetic Specifications

DC Operating Parameters: V_{DD} = 1.6V to 3.6V

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Operating Point	B_{OP}	T_A = 25°C	0.5	2	4	mT
Release Point	B_{RP}		-4	-2	-0.5	mT
Hysteresis	B_{HYST}		1.5	4	7	mT
Operating Point	B_{OP}	T_A = -40 to 85°C	0.1	2	5	mT
Release Point	B_{RP}		-5	-2	-0.1	mT
Hysteresis	B_{HYST}		1.5	4	7	mT

Table 5: Magnetic specifications

9. Application Section

9.1. Application Schematics

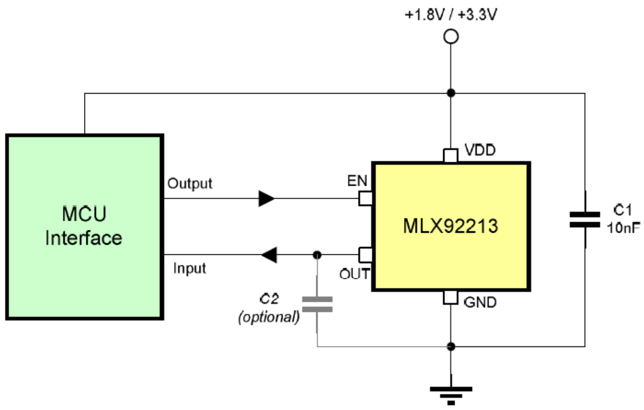


Fig.1 – Enhanced Power Management
Typical 1.8V or 3.3V application with MCU interface reading the OUT signal and driving the EN signal

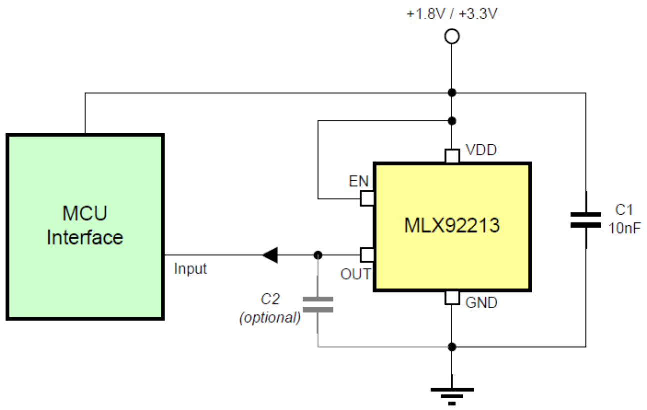


Fig.2 – Standard Power Management
1.8V or 3.3V application with MCU interface reading the OUT signal with default "Micropower"

9.2. Recommendation / Comments

A bypass capacitor C1 of 10nF is recommended to ensure supply voltage stability in application. It should be placed between the V_{DD} and GND pin, as close as possible to the MLX92213.

The MLX92213 provides a direct push-pull output, hence aiming to reduce external component count like output pull-up resistor or capacitor. The use of the output capacitor C2 connected in parallel to the output is optional. If connected between OUT and GND in such a push-pull configuration, the current sinked by the charge of the capacitor when the output switches from "0" to "1" leads to an small increase of the average current consumption of the whole module (IC + capacitor).
Using small capacitor value C2 (less than 50pF) would avoid having such small increase of the module average current consumption.

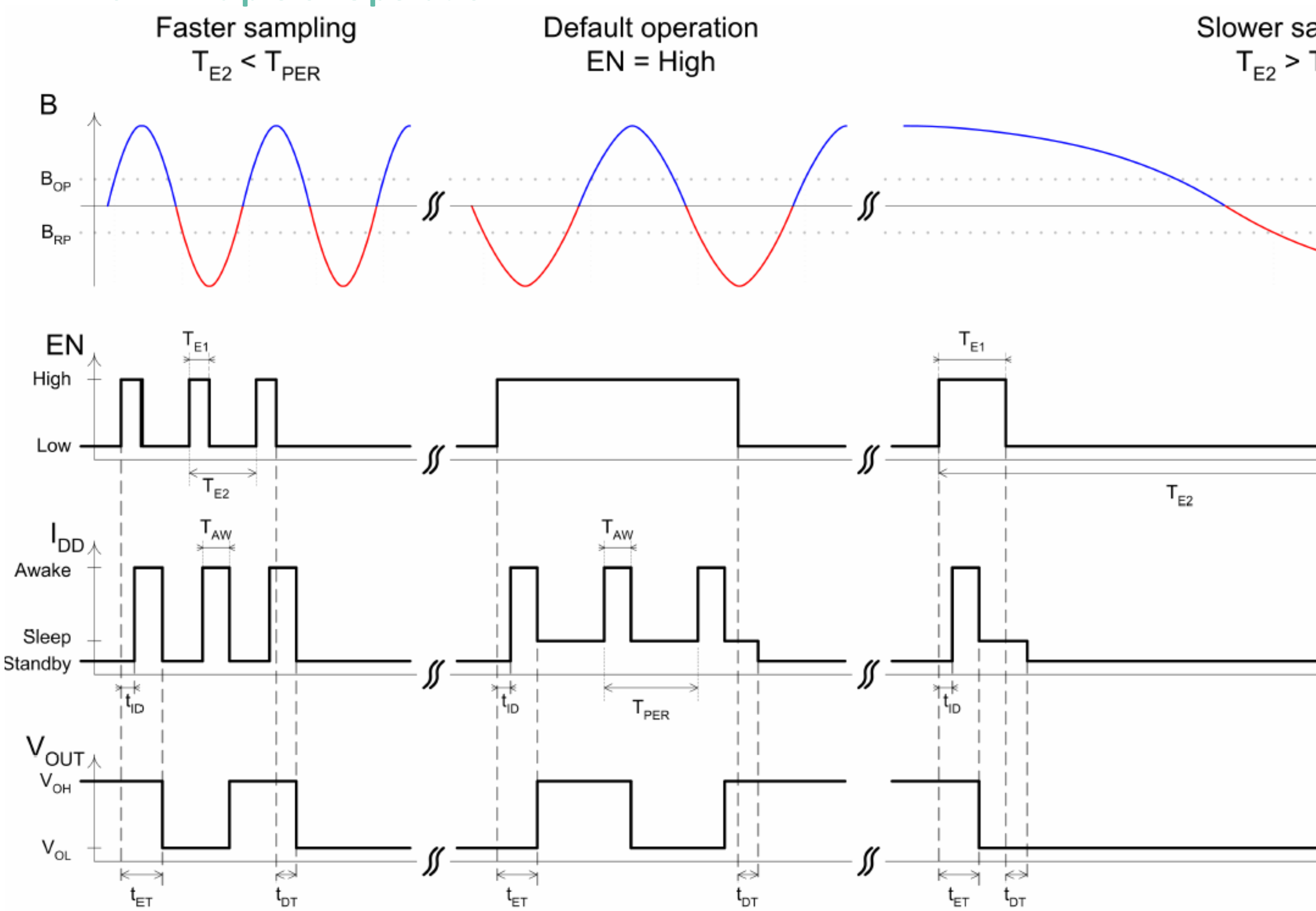
For enhanced power management, the EN (Enable) signal can be driven by an external MCU. It basically allows controlling the state IC and therefore its current consumption according the application requirements:

- Standby mode for minimal current consumption (EN = "0")
- Default Micropower (EN = "1")
- Faster or slower sampling rate through EN signal

For more details on the different mode, please refer to the Principle of Operation section.

For application where standard power management is enough (default "Micropower" mode, Standby unused), the EN pin should be tied to VDD

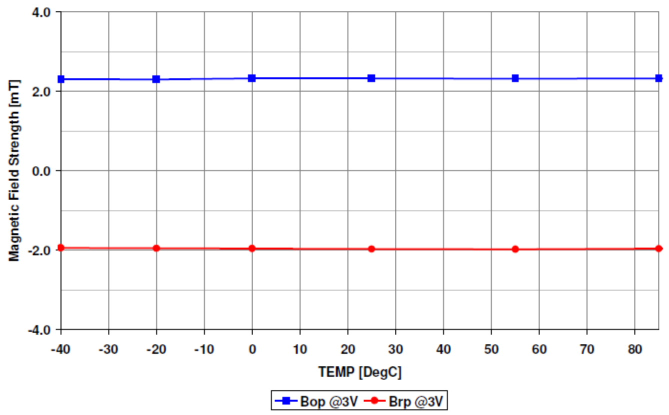
10. Principle of Operation



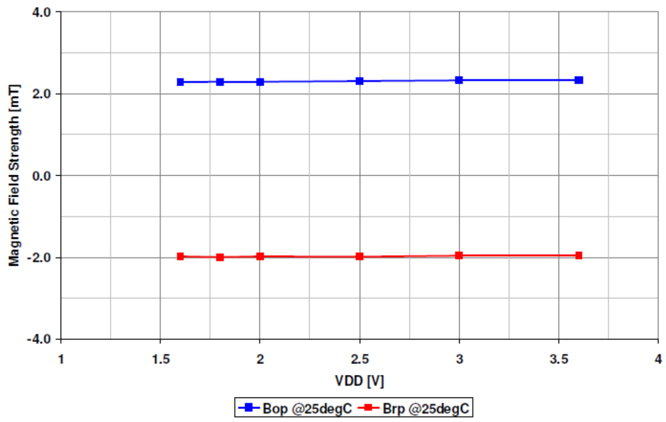
Note: The diagrams are not-to-scale, for exact values refer to General Electrical Specifica
Note: The Output is assumed to have only a low capacitive load, which results in fast rise / fall times

11. Performance Graphs

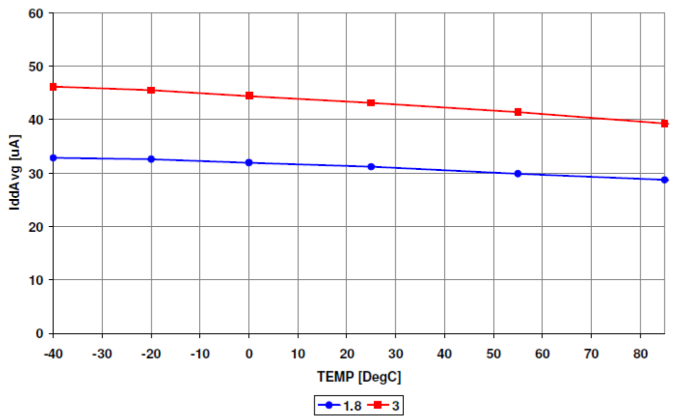
11.1. Magnetic Threshold vs. Temperature



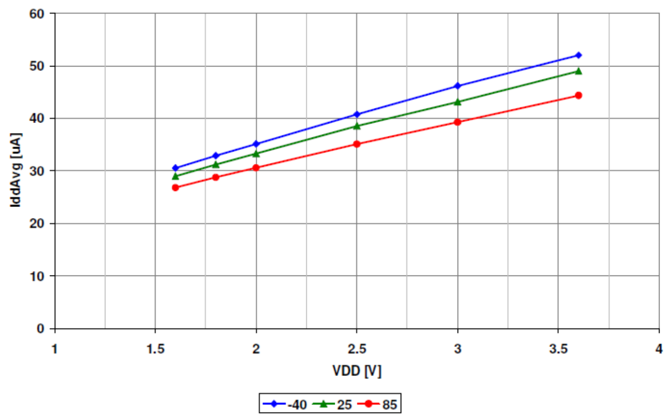
11.2. Magnetic Threshold vs. Supply Voltage



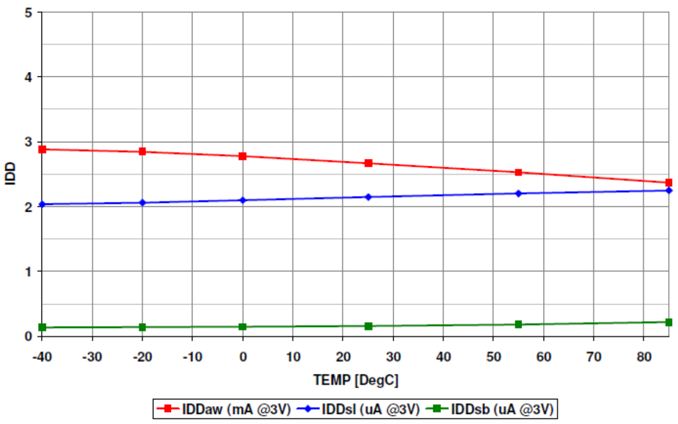
11.3. Average Supply Current vs. Temperature



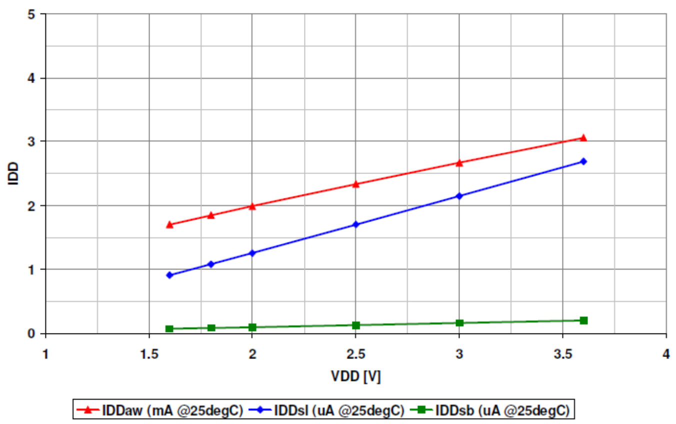
11.4. Average Supply Current vs. Supply *Voltage*



11.5. Supply Current vs. Temperature



11.6. Supply Current vs. Supply Voltage



12. Standard information regarding manufacturability of Melexis products with different soldering processes

Our products are classified and qualified regarding soldering technology, solderability and moisture sensitivity level according to following test methods:

Reflow Soldering SMD's (Surface Mount Devices)

- IPC/JEDEC J-STD-020
  Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices
  (classification reflow profiles according to table 5-2)
- EIA/JEDEC JESD22-A113
  Preconditioning of Nonhermetic Surface Mount Devices Prior to Reliability Testing
  (reflow profiles according to table 2)

Wave Soldering SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EN60749-20
  Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat
- EIA/JEDEC JESD22-B106 and EN60749-15
  Resistance to soldering temperature for through-hole mounted devices

Iron Soldering THD's (Through Hole Devices)

- EN60749-15
  Resistance to soldering temperature for through-hole mounted devices

Solderability SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EIA/JEDEC JESD22-B102 and EN60749-21
  Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

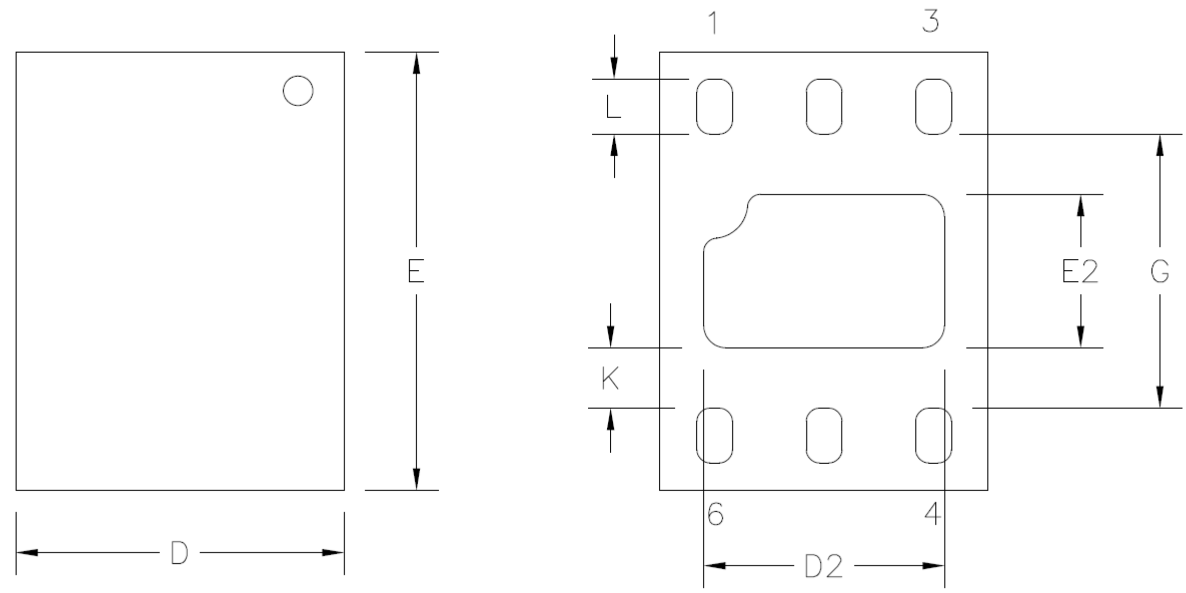
The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

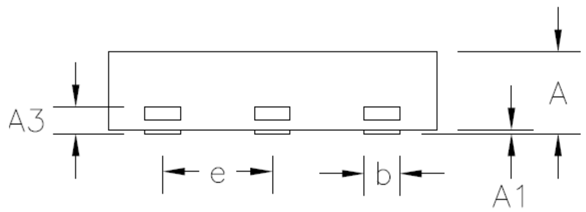
Melexis is contributing to global environmental conservation by promoting **lead free** solutions. For more information on qualifications of **RoHS** compliant products (RoHS = European directive on the Restriction Of the use of certain Hazardous Substances) please visit the quality page on our website: http://www.melexis.com/quality.aspx

13. ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD).
Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

14. LD Package (UTQFN-6L)



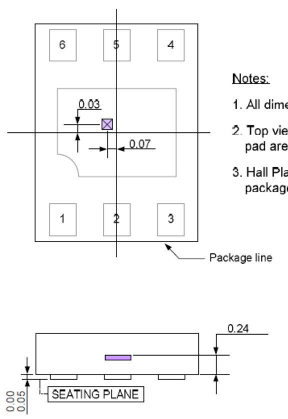


Marking:

1st Line : .13
"." (dot) - used to show the 1st pin
13 - Name of the device (MLX92213)

2nd Line : YWW
Y - Year (last digit)
WW - Calendar Week

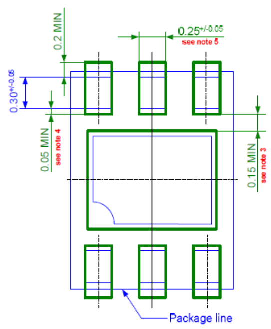
Hall plate location



Notes:

1. All dimensions are in millimeters.
2. Top view is represented. Terminals and exposed pad are for illustration only.
3. Hall Plate position in X and Y axis relative to package center

Land Pattern



LD package dimensions - Blue
Corresponding land pattern - Green

Notes:

1. All dimensions are in millimeters.
2. Top view is represented. Package pads and outline are for reference.
3. Recommended minimal distance to prevent solder bridging.
4. Recommended distance for good solder filleting.
5. Due to lead pitch lower than 0.65mm, pad width should be limited to width of component terminal to reduce risk of solder bridging.
6. To enable thermal and electrical characteristics enhancement, the Exposed Pad must be connected to the PCB substrate with solder.
7. Exposed pad land pattern should be extended whenever possible. Therefore, its width is not limited whereas its height should respect the minimal distance as mentioned in note 3.
8. Land pattern based on package supplier's specification.

This table in mm

D x E	N	e		A	A1	A3	D2	E2	G	L	K	b
1.5 x 2	6	0.50	min	0.31	0.00	0.13	0.95	0.55	1.20	0.22	0.20	0.18
			max	0.40	0.05	REF	1.20	0.90	1.30	0.43	–	0.30

Note:
1. General tolerance of D and E is ±0.1mm.
2. Bottom pin1 identification is may vary depends on the suppliers.

15. Contact

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